TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT process)

2SC2459

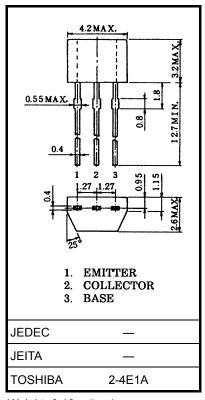
Audio Amplifier Applications

Unit: mm

- High breakdown voltage: VCEO = 120 V (max)
- High DC current gain: $h_{FE} = 200 \sim 700$
- Excellent hFE linearity: hFE ($I_C = 0.1 \text{ mA}$)/hFE ($I_C = 2 \text{ mA}$) = 0.95 (typ.)
- Low noise: NF = 1dB (typ.), 10dB (max)
- Complementary to 2SA1049.
- · Small package.

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	120	V
Collector-emitter voltage	V_{CEO}	120	V
Emitter-base voltage	V_{EBO}	5	V
Collector current	IC	100	mA
Base current	ΙΒ	20	mA
Collector power dissipation	PC	200	mW
Junction temperature	Tj	125	°C
Storage temperature range	T _{stg}	−55~125	°C



Weight: 0.13 g (typ.)

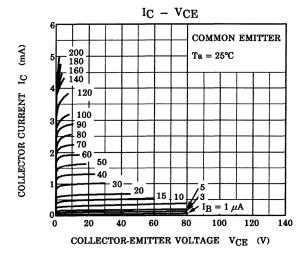
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in

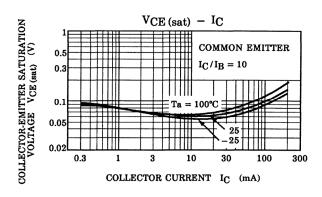
temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

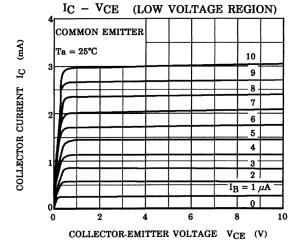
Electrical Characteristics (Ta = 25°C)

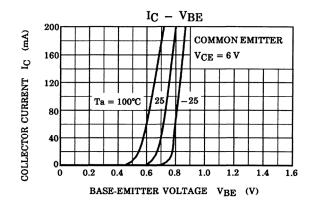
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	V _{CB} = 120 V, I _E = 0	_	_	0.1	μΑ
Emitter cut-off current	I _{EBO}	V _{EB} = 5 V, I _C = 0			0.1	μА
DC current gain	h _{FE} (Note)	V _{CE} = 6 V, I _C = 2 mA	200	_	700	
Collector-emitter saturation voltage	V _{CE} (sat)	$I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$	_	_	0.3	V
Transition frequency	f _T	V _{CE} = 6 V, I _C = 1 mA	_	100		MHz
Collector output capacitance	C _{ob}	$V_{CB} = 10 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$	_	3.0		pF
Noise figure	NF	$V_{CE} = 6 \text{ V}, I_{C} = 0.1 \text{ mA},$ f = 1 kHz, R _G = 10 k Ω		1.0	10	dB

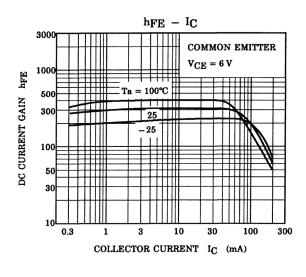
Note: hFE classification GR: 200~400, BL: 350~700

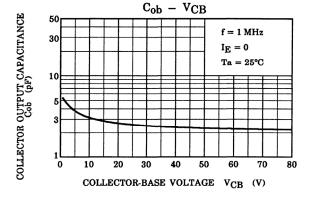


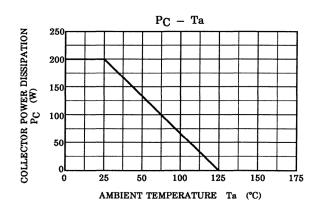












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20070701-EN GENERAL

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